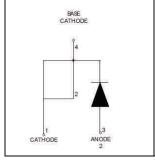
International

Features

- Ultrafast Recovery
- Ultra soft Recovery
- Very Low I_{RRM}
- Very Low Q_{rr}
- Specified at Operating Conditions
- Lead-Free

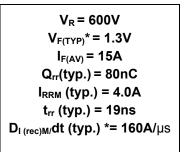
Benefits

- Reduced RFI and EMI
- · Reduced Power Loss in Diode and Switching Transistor
- Higher Frequency Operation
- Reduced Snubbing
- Reduced Parts Count



HFA15PB60PbF

Ultrafast, Soft Recovery Diode





Description

International Rectifier's HFA15PB60 is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 volts and 15 amps continuous current, the HFA15PB60 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultra fast recovery time, the ultrafast recovery diode product line features extremely low values of peak recovery current (IRRM) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The ultrafast recovery diode features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These ultrafast advantages can help to significantly reduce snubbing, component count and heat sink sizes. The HFA15PB60 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

		Standard Pack		
Base part number	Package Type	Form	Quantity	Orderable Part Number
HFA15PB60PbF	TO-247AC	Tube	25	HFA15PB60PbF

Absolute Maximum Ratings

	Parameter	Max.	Units
V _R	Cathode -to – Anode Voltage	600	V
I _F @ T _C = 100°C	Continuous Forward Current	15	
I _{FSM}	Single Pulse Forward Current	150	А
I _{FRM}	Maximum Repetitive Forward Current	60	
P _D @T _C = 25°C	Maximum Power Dissipation	74	14/
P _D @T _C = 100°C	Maximum Power Dissipation	29	— W
TJ	Operating Junction and	55 1 1 150	
T _{STG}	Storage Temperature Range	-55 to + 150	°C

* 125°C

1



HFA15PB60PbF

	Parameter	Min.	Тур.	Max.	Units	Conditions
V_{BR}	Cathode Anode Breakdown Voltage	600				Ι _R = 100μΑ
			1.3	1.7	v	I _F = 15A See Fig. 1
V _{FM} Max F	Max Forward Voltage		1.5	2.0		I _F = 30A
			1.2	1.6		I _F = 30A ,T _J = 125°C
1	Max Davaraa Laakaga Current		1.0	10		$V_R = V_R$ Rated See Fig. 2
IRM	Max Reverse Leakage Current		400	1000	μA	$T_{J} = 125^{\circ}C, V_{R} = 0.8 \text{ x } V_{R} \text{ Rated}$
Ст	Junction Capacitance		25	50	pF	V _R = 200V See Fig. 3
Ls	Series Inductance		12		nH	Measured lead to lead 5mm from package body

Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

Dynamic Recovery Characteristics @ TJ = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
trr			19			I_F = 1.0A, dif/dt = 200A/µs, V_R = 30V
trr1	Reverse Recovery Time See Fig. 5,10		42	60	ns	$T_J = 25^{\circ}C$
trr2			74	120		T _J = 125°C
I _{RRM1}	Peak Recovery Current See Fig. 6		4.0	6.0	А	T _J = 25°C I _F =15A
I _{RRM2}	r eak Necovery Current See Fig. 0		6.5	10		T _J = 125°C V _R =200V
Q _{rr1}	Deverse Desever Charge See Fig 7	_	80	180		T _J = 25°C di/dt = 200A/μs
Q _{rr2}	Reverse Recovery Charge See Fig.7		220	600	nC	T _J = 125°C
di _{(rec)M/} dt1	Peak Rate of Fall of Recovery Current		188		A /	$T_J = 25^{\circ}C$
di _{(rec)M/} dt2	During tb See Fig.8		160		A/µs	T _J = 125°C

Thermal – Mechanical Characteristics

	Parameter	Min.	Тур.	Max.	Units
T _{lead} ①	Lead Temperature			300	°C
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case			1.7	
R _{θJA} ②	Thermal Resistance, Junction to Ambient			40	K/W
R _{θCS} ③	Thermal Resistance, Case to Heat Sink		0.25		
	Maisht		6.0		g
Wt	Weight		0.21		(oz)
т	Mounting Torque	6.0		12	Kg-cm
	Mounting Torque	5.0		10	lbf•in

① 0.063 in. from Case (1.6mm) for 10 sec

- ② Typical Socket Mount
- ③ Mounting Surface, Flat, Smooth and Greased

2



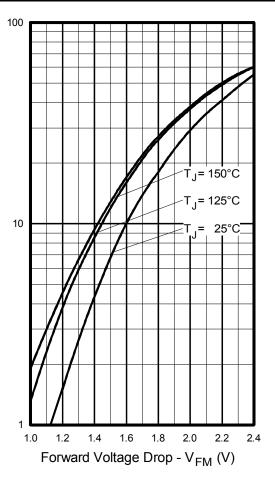


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

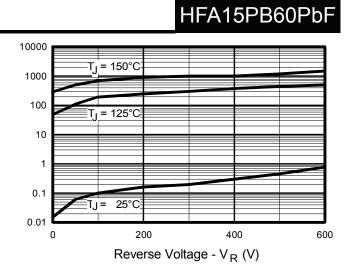


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

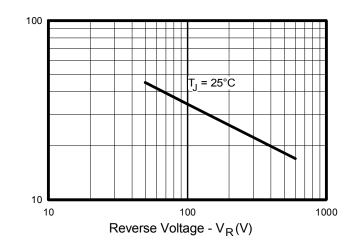


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

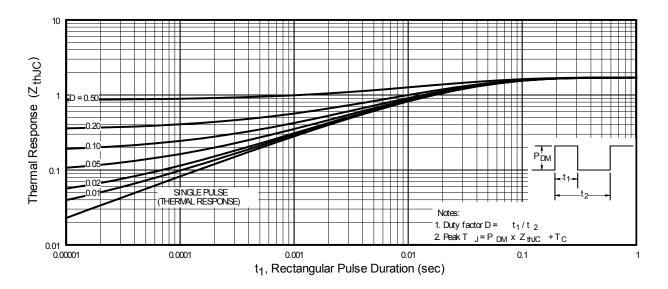


Fig. 4 - Maximum Thermal Impedance Zthjc Characteristics

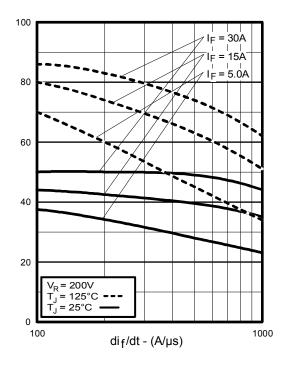


Fig. 5 - Typical Reverse Recovery vs. dif/dt

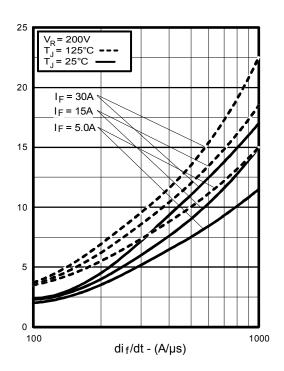
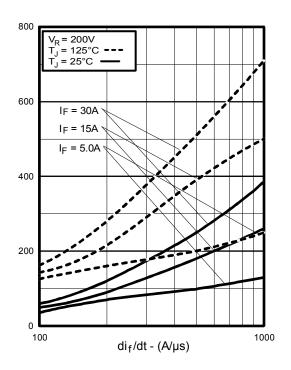
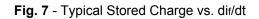


Fig. 6 - Typical Recovery Current vs. dif/dt





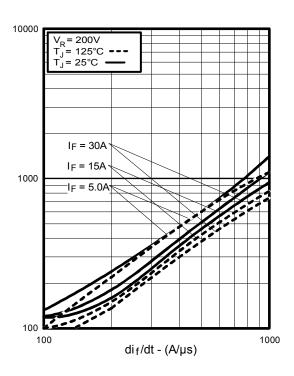


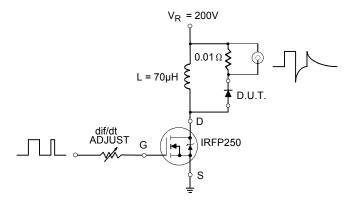
Fig. 8 - Typical di(rec)M/dt vs. dif/dt

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REVERSE RECOVERY CIRCUIT



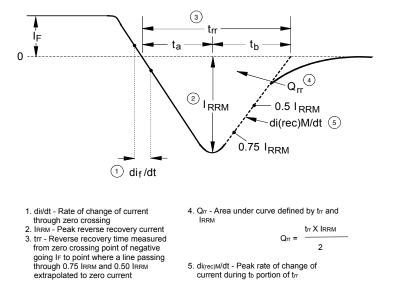
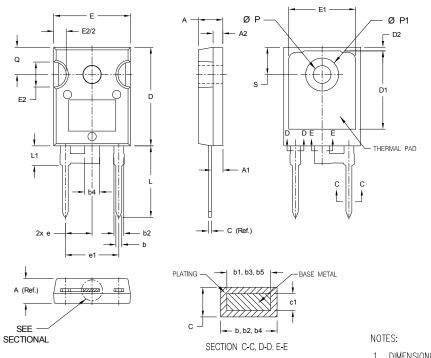


Fig. 9 - Reverse Recovery Parameter Test Circuit

Fig. 10 - Reverse Recovery Waveform and Definitions

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TO-247AC Package Outline (Dimensions are shown in millimeters (inches))

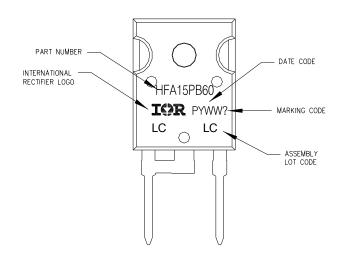


04/00	MILLIM	ETERS	INCHES		
SYMBOL	MIN.	MAX.	MIN.	MAX.	
А	4.65	5.31	.1831	.2091	
A1	2.21	2.59	.0870	.1020	
A2	1.50	2.49	.0591	.0980	
b	0.99	1.40	.0390	.0551	
b1	0.99	1.35	.0390	.0531	
b2	1.65	2.39	.0650	.0941	
b3	1.65	2.34	.0650	.0921	
b4	2.59	3.43	.1020	.1350	
b5	2.59	3.38	.1020	.1331	
С	0.38	0.89	.0150	.0350	
c1	0.38	0.84	.0150	.0331	
D	19.71	20.70	.7760	.8150	
D1	13.08		.5150		
D2	0.51	1.35	.0201	.0531	
E	15.29	15.87	.6020	.6248	
E1	13.46		.5299		
E2	4.52	5.49	.1780	.2161	
е	5.46 BASIC		.2150 BASIC		
L	14.20	16.10	.5591	.6339	
L1	3.71	4.29	.1461	.1689	
Q	5.31	5.69	.2091	.2240	
S	5.51	BASIC	.2169	BASIC	
øР	3.56	3.66	.1402	.1441	
ØP1		7.39		.2909	

1. DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M 1994.

2. DIMENSIONS ARE SHOWN IN MILLIMETERS [INCHES].

TO-247AC Part Marking Information



Note: For the most current drawing please refer to IR website at http://www.irf.com/package/

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Qualification Information[†]

	Industrial				
Qualification Level	(per JEDEC JESD47F) ^{††}				
Moisture Sensitivity Level	TO-247AC	N/A			
RoHS Compliant	Yes				

+ Qualification standards can be found at International Rectifier's web site: <u>http://www.irf.com/product-info/reliability/</u>

t Applicable version of JEDEC standard at the time of product release.

International ICR Rectifier IR WORLD HEADQUARTERS: 101 N. Sepulveda Blvd., El Segundo, California 90245, USA To contact International Rectifier, please visit <u>http://www.irf.com/whoto-call/</u>